

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL JUNCTION TYPE

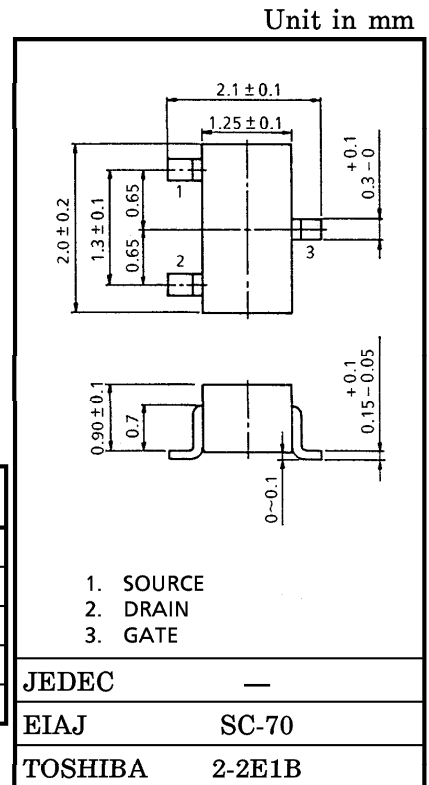
# 2SK879

GENERAL PURPOSE AND IMPEDANCE CONVERTER AND CONDENSER MICROPHONE APPLICATIONS

- High Breakdown Voltage :  $V_{GDS} = -50V$
- High Input Impedance :  $I_{GSS} = -1.0nA$  (Max.) ( $V_{GS} = -30V$ )
- Low Noise :  $NF = 0.5dB$  (Typ.) ( $R_G = 100k\Omega$ ,  $f = 120Hz$ )
- Small Package

MAXIMUM RATINGS ( $T_a = 25^\circ C$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	$V_{GDS}$	-50	V
Gate Current	$I_G$	10	mA
Drain Power Dissipation	$P_D$	100	mW
Junction Temperature	$T_j$	125	$^\circ C$
Storage Temperature Range	$T_{stg}$	-55~125	$^\circ C$



ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ C$ )

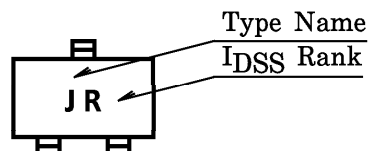
Weight : 0.006g

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Cut-off Current	$I_{GSS}$	$V_{GS} = -30V, V_{DS} = 0$	—	—	-1.0	nA
Gate-Drain Breakdown Voltage	$V_{(BR)GDS}$	$V_{DS} = 0, I_G = -100\mu A$	-50	—	—	V
Drain Current	$I_{DSS}$ (Note)	$V_{DS} = 10V, V_{GS} = 0$	0.3	—	6.5	mA
Gate-Source Cut-off Voltage	$V_{GS(OFF)}$	$V_{DS} = 10V, I_D = 0.1\mu A$	-0.4	—	-5.0	V
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 10V, V_{GS} = 0, f = 1kHz$	1.2	—	—	mS
Input Capacitance	$C_{iss}$	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$	—	8.2	—	pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{GD} = -10V, I_D = 0, f = 1MHz$	—	2.6	—	pF
Noise Figure	NF	$V_{DS} = 15V, V_{GS} = 0$ $R_G = 100k\Omega, f = 120Hz$	—	0.5	—	dB

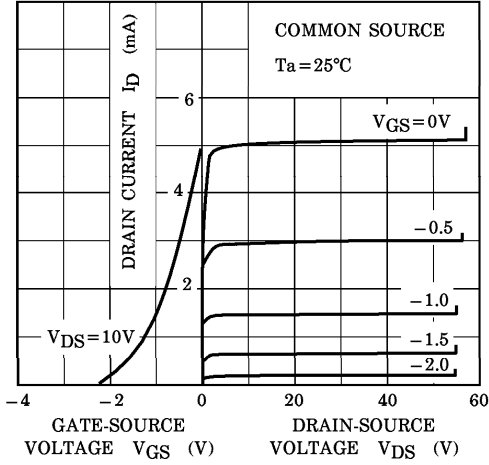
Note :  $I_{DSS}$  Classification

R : 0.30~0.75mA, O : 0.60~1.40mA  
Y : 1.2~3.0mA, GR : 2.6~6.5mA

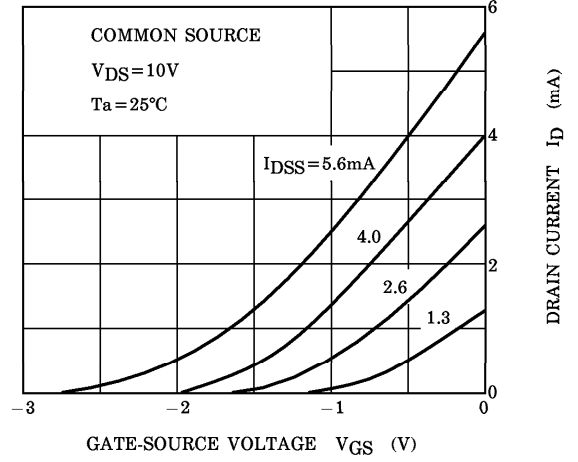
Marking



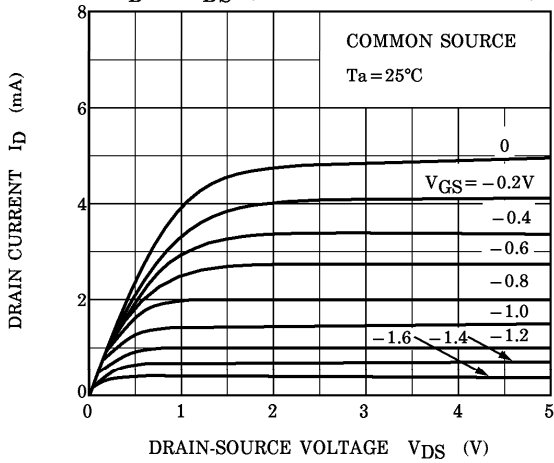
STATIC CHARACTERISTICS



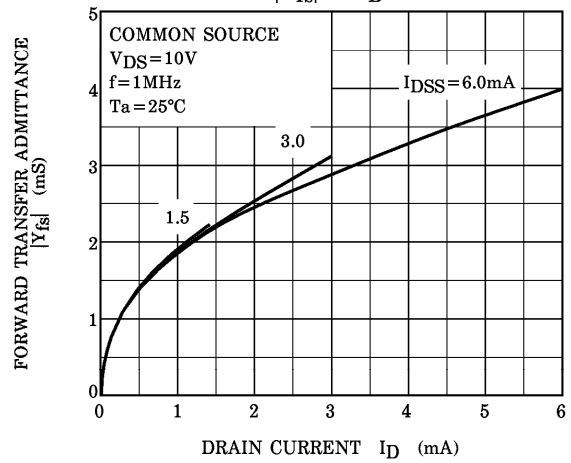
$I_D - V_{GS}$



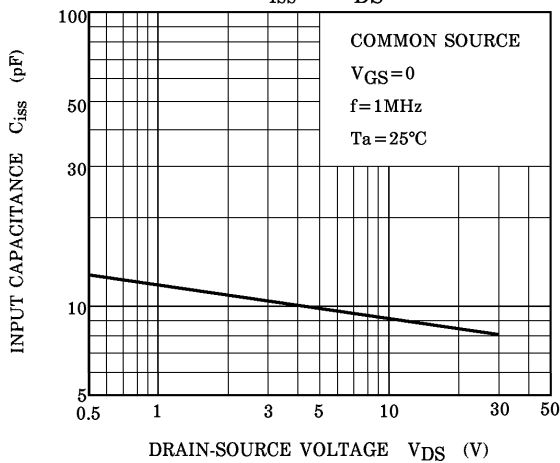
$I_D - V_{DS}$  (LOW VOLTAGE REGION)



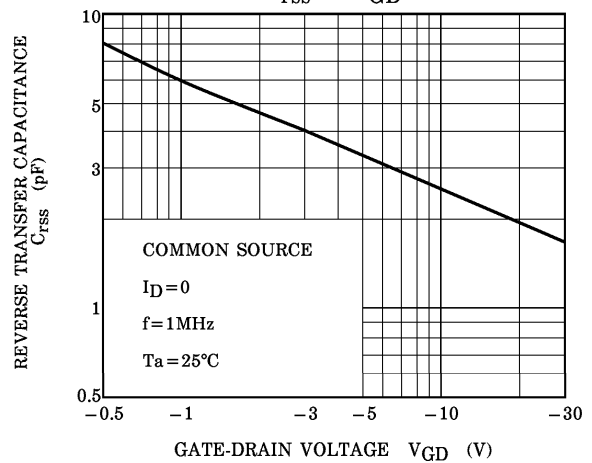
$|Y_{fs}| - I_D$

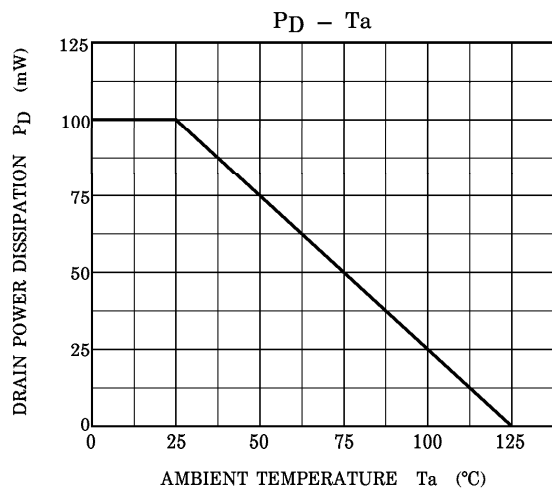
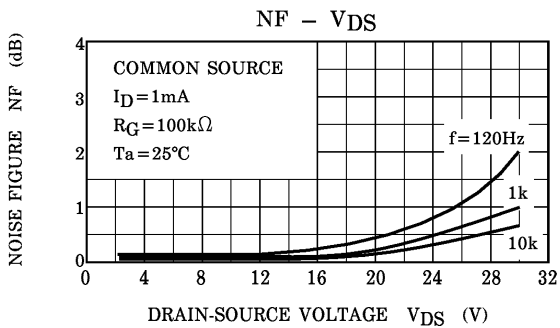
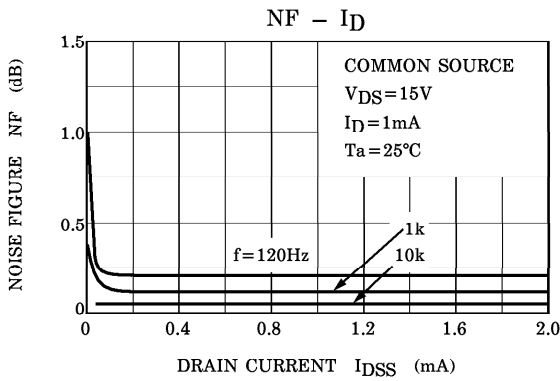
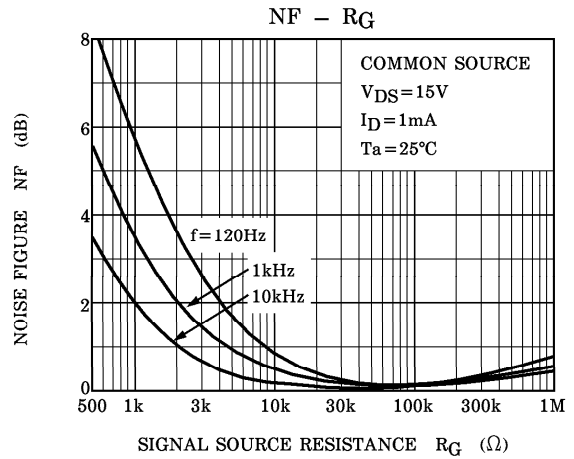
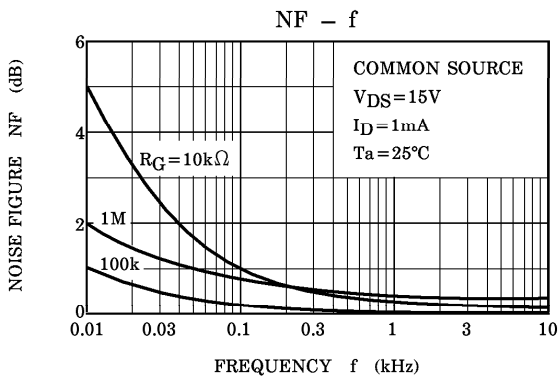
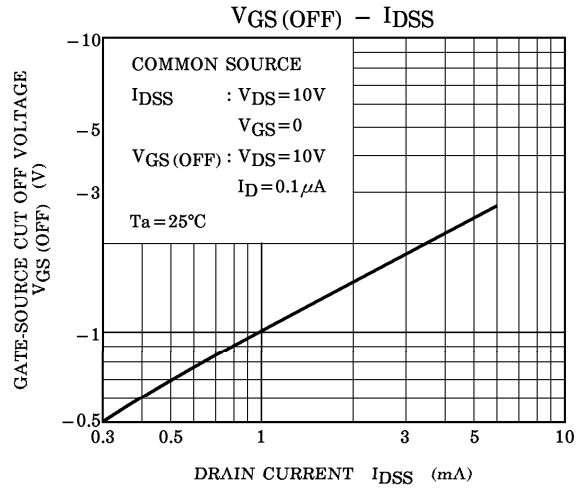
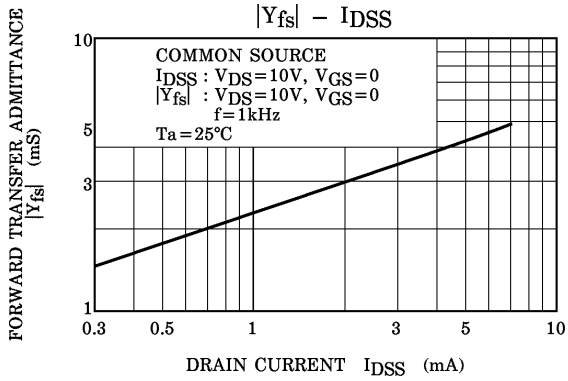


$C_{iss} - V_{DS}$



$C_{rss} - V_{GD}$





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